L Number	Hits	Search Text	DB	Time stamp
-	8	hsg same arsenic and polysilicon and ono and rom	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/04/11 23:01
-	50	hsg same arsenic and polysilicon and ono and plug	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/11 23:09
-	29	hsg with arsenic and polysilicon and ono and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/11 23:01
-	59	hsg same arsenic and polysilicon and (one or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 15:17
-	1	"6410385".PN.	USPAT	2004/04/12 13:28
_	1	"6154864".PN.	USPAT	2004/04/12
-	226	hsg and polysilicon and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12
_	1	"09928308"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 16:08
_	. 1	"6410385".PN.	USPĀT	2004/04/12 16:10
_	10	hsg same polysilicon same (ono or "ta.sub.2o.sub.5") same plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 17:20
-	91	hsg same polysilicon same etch\$3 and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12
-	2	hsg with arsenic same polysilicon same etch\$3 and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 17:23
_	5	hsg same arsenic same polysilicon same etch\$3 and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12
-	1	hsg with etch\$3 same arsenic same polysilicon and (one or "ta.sub.20.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 17:25
-	242	hemispherical adj grain and polysilicon and ono	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/14

				<u>,</u>
_	19	hemispherical adj grain and polysilicon and ono and "in situ"	USPAT; US-PGPUB; EPO; JPO;	2004/04/14 22:24
			DERWENT; IBM_TDB	0004/04/14
-	0	hemispherical adj grain and polysilicon and ono and "in situ" same arsenic	USPAT; US-PGPUB; EPO; JPO;	2004/04/14 22:24
			DERWENT; IBM_TDB	2024/04/14
-	19	hemispherical adj grain and polysilicon and ono and "in situ"	USPAT; US-PGPUB; EPO; JPO;	2004/04/14 22:26
	85	hemispherical adj grain and polysilicon	DERWENT; IBM_TDB USPAT;	2004/04/14
		and one and arsenic	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	22:27
_	85	hemispherical adj grain and polysilicon and ono and arsenic and dram	USPAT; US-PGPUB; EPO; JPO;	2004/04/14 22:28
			DERWENT; IBM_TDB	
_	54	hemispherical adj grain and polysilicon and ono and arsenic and plug	USPAT; US-PGPUB; EPO; JPO;	2004/04/14 22:31
-	39	"5995409" "6134137" "6154864" "6243285" "6410385"	DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/04/14 23:01
		0410303	EPO; JPO; DERWENT; IBM TDB	23.01
_	0	("59954096134137615486462432856410385").PN	.USPAT; US-PGPUB; EPO; JPO;	2004/04/14 23:00
_	39	"5995409" "6134137" "6154864" "6243285" "6410385"	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/04/14 23:20
_	1	"6300191".PN.	IBM_TDB USPAT	2004/04/14
_	1	"6251726".PN.	USPAT	23:05 2004/04/14 23:05
_	1	"6221711".PN.	USPAT	2004/04/14
-	1	"6187624".PN.	USPAT	2004/04/14 23:05
-	1	"6187624".PN.	USPAT	2004/04/14 23:06
-	1	"6140172".PN.	USPAT	2004/04/14 23:06
	1	"6134137".PN.	USPAT	2004/04/14 23:11
_	1	"6100137".PN. "6046093".PN.	USPAT	2004/04/14 23:11 2004/04/14
_	1	"5989952".PN.	USPAT	23:11 2004/04/14
_	0	"6140172" and ono	USPAT;	23:12 2004/04/14
			US-PGPUB; EPO; JPO; DERWENT; IBM TDB	23:20
				L

_	0	"6140172" and arsenic	USPAT;	2004/04/14
			US-PGPUB;	23:20
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	69	hsg same arsenic and polysilicon and ono	USPAT;	2004/04/15
			US-PGPUB;	15:35
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	11	"6545899"	USPAT;	2004/04/15
}			US-PGPUB;	15:36
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	